

NHUMH11/1/2 series

80 V, 100 mA NPN/NPN resistor-equipped double transistors

Rev. 1 — 22 July 2020 Product data sheet

1. General description

NPN/NPN Resistor-Equipped double Transistor (RET) family in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	R1	1 R2 Package		Package		NPN/PNP
	kΩ	kΩ	Nexperia	JEITA	complement:	complement:
NHUMH11	10	10	SOT363	SC-88	NHUMB11	NHUMD3
NHUMH1	22	22			NHUMB1	NHUMD2
NHUMH2	47	47			NHUMB2	NHUMD12

2. Features and benefits

- 100 mA output current capability
- High breakdown voltage
- · Built-in resistors
- · Simplifies circuit design
- · Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

3. Applications

- · Digital applications
- Cost saving alternative for BC846 series in digital applications
- Controlling IC inputs
- Switching loads

4. Quick reference data

Table 2. Quick reference data

T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
Per transistor							
V_{CEO}	collector-emitter voltage	open base	-	-	80	V	
Io	output current		-	-	100	mA	



5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1	□6 □5 □4	O1 I2 GND2
2	I1	input (base) TR1		
3	O2	output (collector) TR2		R1 R2
4	GND2	GND (emitter) TR2		TR2
5	12	input (base) TR2		TR1 R2 R1
6	O1	output (collector) TR1		
				GND1 I1 O2
				aaa-019894

6. Ordering information

Table 4. Ordering information

Type number	Package					
	Name	Description	Version			
NHUMH11	SC-88	plastic surface-mounted package; 6 leads	SOT363			
NHUMH1						
NHUMH2						

7. Marking

Table 5. Marking

Type number	Marking code [1]				
NHUMH11	6F%				
NHUMH1	6J%				
NHUMH2	6L%				

[1] % = placeholder for manufacturing site code

8. Limiting values

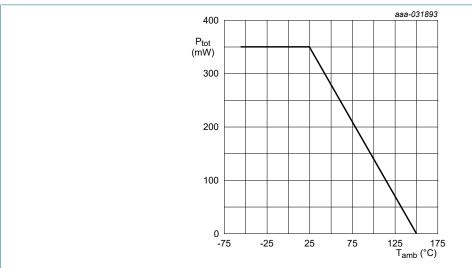
Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Max	Unit		
Per transis	tor							
V _{CBO}	collector-base voltage	open emitter		-	80	V		
V _{CEO}	collector-emitter voltage	open base		-	80	V		
V _{EBO}	emitter-base voltage	open collector		-	10	V		
V _I	input voltage							
	NHUMH11			-10	+40	V		
	NHUMH1			-10	+60	V		
	NHUMH2			-10	+80	V		
Io	output current			-	100	mA		
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	235	mW		
Per device					'			
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	350	mW		
T _j	junction temperature			-	150	°C		
T _{amb}	ambient temperature			-55	150	°C		
T _{stg}	storage temperature			-65	150	°C		

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.



FR4 PCB, single-sided copper, standard footprint

Fig. 1. Per device: Power derating curve SOT363 (SC-88)

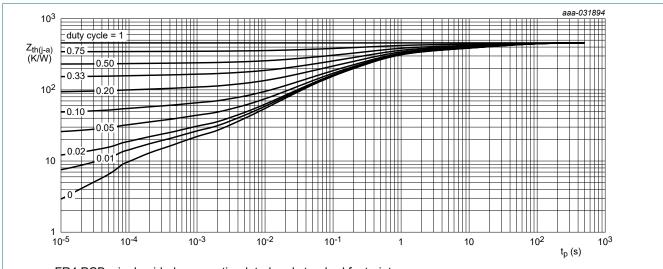
9. Thermal characteristics

Table 7. Thermal characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per transistor								
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	532	K/W	
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	150	K/W	
Per device								
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	358	K/W	

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.



FR4 PCB, single-sided copper, tin-plated and standard footprint

Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

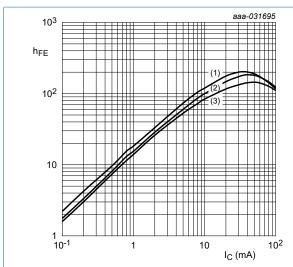
Table 8. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit		
Per transis	tor								
V _{(BR)CBO}	collector-base breakdown voltage	I _C = 100 μA; I _E = 0 A		80	-	-	V		
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}$		80	-	-	V		
I _{CBO}	collector-base cut-off current	V _{CB} = 80 V; I _E = 0 A		-	-	100	nA		
I _{CEO}	collector-emitter cut-off	V _{CE} = 60 V; I _B = 0 A		-	-	100	nA		
	current	V _{CE} = 60 V; I _B = 0 A; T _j = 150 °C		-	-	5	μA		
I _{EBO}	emitter-base cut-off curr	ent					_		
	NHUMH11	V _{EB} = 7 V; I _C = 0 A		-	-	600	μA		
	NHUMH1			-	-	270	μA		
	NHUMH2			-	-	130	μA		
h _{FE}	DC current gain								
	NHUMH11	V _{CE} = 5 V; I _C = 10 mA		50	-	-			
	NHUMH1			70	-	-			
	NHUMH2			100	-	-			
V _{CEsat}	collector-emitter saturation voltage	I _C = 10 mA; I _B = 0.5 mA		-	-	100	mV		
V _{I(off)}	off-state input voltage	V _{CE} = 5 V ; I _C = 100 μA		-	1.15	0.8	V		
V _{I(on)}	on-state input voltage								
	NHUMH11	$V_{CE} = 0.3 \text{ V}$; $I_{C} = 10 \text{ mA}$		2.5	1.8	-	V		
	NHUMH1			3	2.3	-	V		
	NHUMH2			5	3.3	-	V		
R1	bias resistor 1 (input)	[1]							
	NHUMH11			7	10	13	kΩ		
	NHUMH1			15.4	22	28.6	kΩ		
	NHUMH2	1		33	47	61	kΩ		
R2/R1	bias resistor ratio		[1]	0.8	1	1.2			
f _T	transition frequency	V _{CE} = 5 V; I _C = 10 mA; f = 100 MHz	[2]	-	170	-	MHz		
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$		-	-	2.5	pF		

^[1] See section "Test information" for resistor calculation and test conditions

^[2] Characteristics of built-in transistor

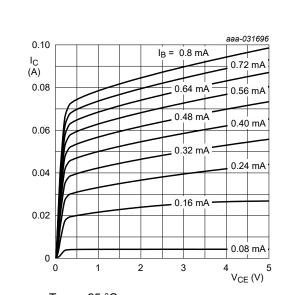


$$V_{CE} = 5 V$$

(2)
$$T_{amb}$$
 = 25 °C

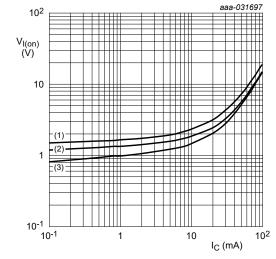
(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 3. NHUMH11: DC current gain as a function of collector current; typical values



T_{amb} = 25 °C

Fig. 4. NHUMH11: Collector current as a function of collector-emitter voltage; typical values

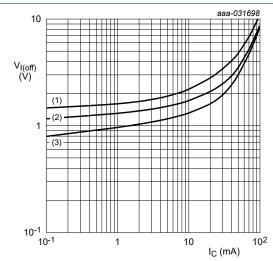


$$V_{CE} = 0.3 V$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

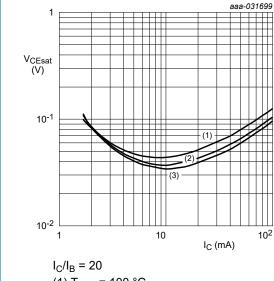
Fig. 5. NHUMH11: On-state input voltage as a function of collector current; typical values



$$V_{CE} = 5 V$$

(1)
$$T_{amb} = -40$$
 °C

Fig. 6. NHUMH11: Off-state input voltage as a function of collector current; typical values

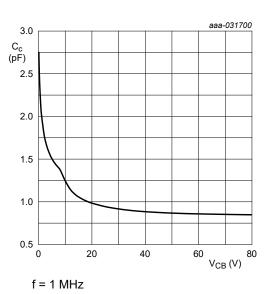


(1) T_{amb} = 100 °C

(2) $T_{amb} = 25 \, ^{\circ}C$

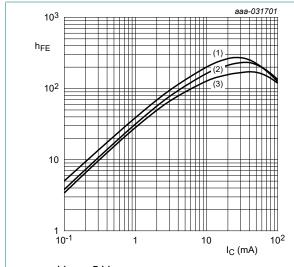
(3) $T_{amb} = -40 \, ^{\circ}C$

Fig. 7. NHUMH11: Collector-emitter saturation voltage as a function of collector current; typical values



 $T_{amb} = 25 \,^{\circ}\text{C}$

Fig. 8. NHUMH11: Collector capacitance as a function of collector-base voltage; typical values



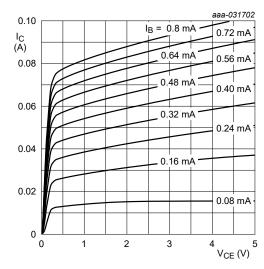
 $V_{CE} = 5 V$

(1) $T_{amb} = 100 \, ^{\circ}C$

(2) T_{amb} = 25 °C

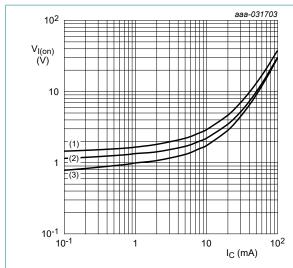
(3) $T_{amb} = -40 \, ^{\circ}C$

Fig. 9. NHUMH1: DC current gain as a function of collector current; typical values



T_{amb} = 25 °C

Fig. 10. NHUMH1: Collector current as a function of collector-emitter voltage; typical values



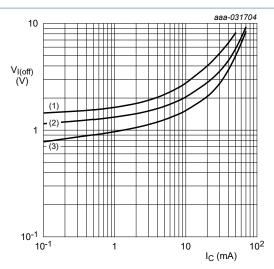
$$V_{CE} = 0.3 V$$

(1)
$$T_{amb}$$
 = -40 °C

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb}$$
 = 100 °C

Fig. 11. NHUMH1: On-state input voltage as a function of collector current; typical values



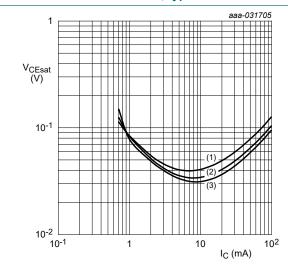
$$V_{CE} = 5 V$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 12. NHUMH1: Off-state input voltage as a function of collector current; typical values



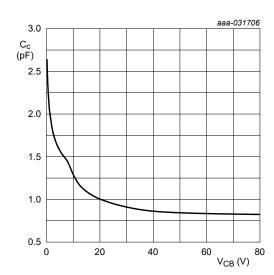
$$I_C/I_B = 20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

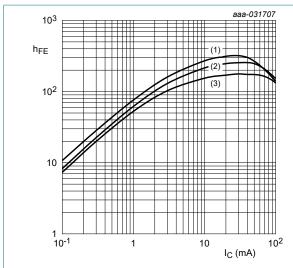
(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 13. NHUMH1: Collector-emitter saturation voltage as a function of collector current; typical values



f = 1 MHz

Fig. 14. NHUMH1: Collector capacitance as a function of collector-base voltage; typical values

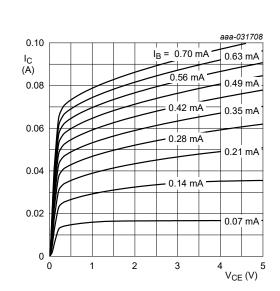


$$V_{CE} = 5 V$$

(1)
$$T_{amb}$$
 = 100 °C

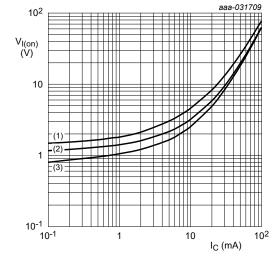
(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 15. NHUMH2: DC current gain as a function of collector current; typical values



 T_{amb} = 25 °C

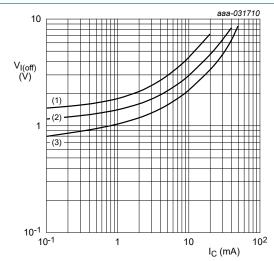
Fig. 16. NHUMH2: Collector current as a function of collector-emitter voltage; typical values



 $V_{CE} = 0.3 V$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

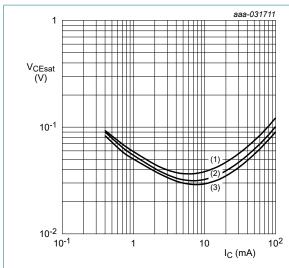
Fig. 17. NHUMH2: On-state input voltage as a function of collector current; typical values



$$V_{CE} = 5 V$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 18. NHUMH2: Off-state input voltage as a function of collector current; typical values



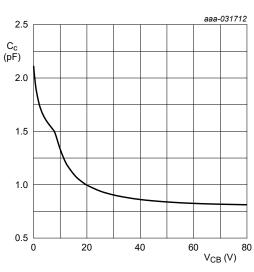
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

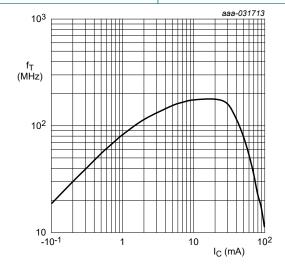
Fig. 19. NHUMH2: Collector-emitter saturation voltage as a function of collector current; typical values



f = 1 MHz

T_{amb} = 25 °C

Fig. 20. NHUMH2: Collector capacitance as a function of collector-base voltage; typical values of built-in transistor



f = 100 MHz

 $V_{CE} = 5 V$

T_{amb} = 25 °C

Fig. 21. Transition frequency as a function of collector current; typical values of built-in transistor

Product data sheet

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

Resistor calculation

Calculation of bias resistor 1 (R1)

$$R_I = \frac{V(I_{I2}) - V(I_{II})}{I_{I2} - I_{II}}$$

Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I14) - V(I13)}{R1 \cdot (I14 - I13)} - 1$$

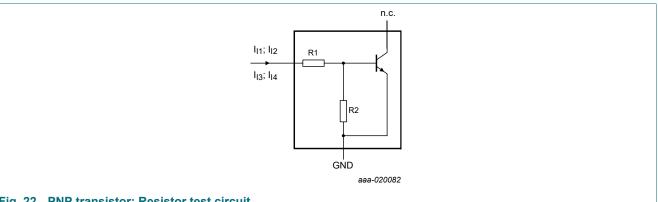


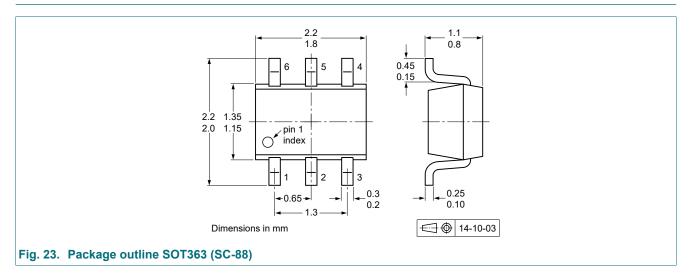
Fig. 22. PNP transistor: Resistor test circuit

Resistor test conditions

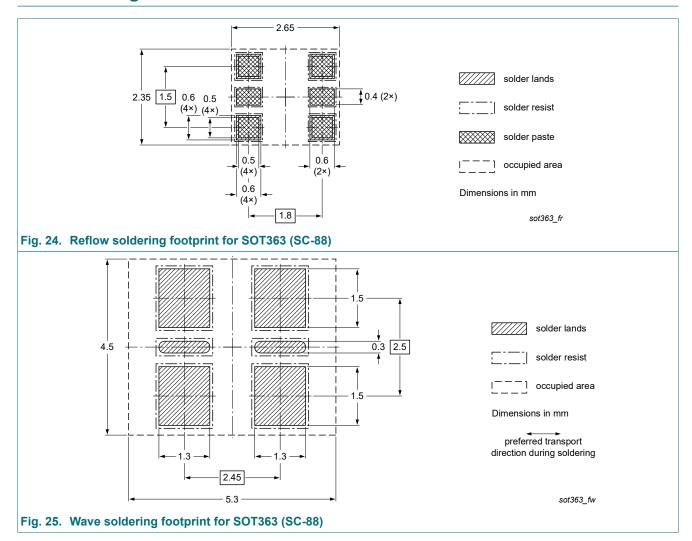
Table 9. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditi	Test conditions				
			I ₁₁	I _{I2}	I _{I3}	I ₁₄		
Per transistor								
NHUMH11	10	10	800 μΑ	1.1 mA	-350 µA	-450 μA		
NHUMH1	22	22	550 μA	750 µA	-150 µA	-230 μΑ		
NHUMH2	47	47	250 μΑ	350 μΑ	-55 μA	-105 μA		

12. Package outline



13. Soldering



14. Revision history

Table 10. Revision history

Data sheet ID	Release date		Change notice	Supersedes
NHUMH11_1_2_SER v.1	20200722	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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Product data sheet

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